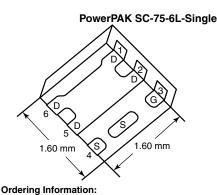


Vishay Siliconix

# P-Channel 20 V (D-S) MOSFET

| PRODUCT SUMMARY     |  |   |                       |  |  |  |  |  |
|---------------------|--|---|-----------------------|--|--|--|--|--|
| V <sub>DS</sub> (V) | <b>R<sub>DS(on)</sub> (</b> Ω <b>)</b> | I <sub>D</sub> (A)                      | Q <sub>g</sub> (Typ.) |  |  |  |  |  |
| - 20                | 0.035 at V <sub>GS</sub> = - 4.5 V     | - 9 <sup>a</sup>                        |                       |  |  |  |  |  |
|                     | 0.049 at V <sub>GS</sub> = - 2.5 V     | <sub>S</sub> = - 2.5 V _ 9 <sup>a</sup> |                       |  |  |  |  |  |
| - 20                | 0.079 at V <sub>GS</sub> = - 1.8 V     |   | 13 nC                 |  |  |  |  |  |
|                     | 0.157 at V <sub>GS</sub> = - 1.5 V     | - 2                                     |                       |  |  |  |  |  |



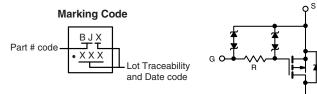
SiB457EDK-T1-GE3 (Lead (Pb)-free and Halogen-free)

#### FEATURES

- Halogen-free According to IEC 61249-2-21
   Definition
- TrenchFET<sup>®</sup> Power MOSFET
- New Thermally Enhanced PowerPAK<sup>®</sup> SC-75 Package
  - Small Footprint Area
- Low On-Resistance
- 100 % R<sub>g</sub> Tested
- Typical ESD Performance: 2500 V
- Built in ESD Protection with Zener Diode
- Compliant to RoHS Directive 2011/65/EU

#### **APPLICATIONS**

- Load Switch for Portable Devices
- Load Switch for Charging Circuits





| ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C, unless otherwise noted)  |   |                                   |  |      |  |  |  |  |
|--|---|-----------------------------------|--|------|--|--|--|--|
| Parameter  |   | Symbol                            | Limit  | Unit |  |  |  |  |
| Drain-Source Voltage   |   | V <sub>DS</sub>                   | - 20   | V    |  |  |  |  |
| Gate-Source Voltage  |   | V <sub>GS</sub>                   | ± 8  | v    |  |  |  |  |
| Continuous Drain Current (T <sub>J</sub> = 150 °C)   | $T_{C} = 25 \text{ °C}$ $T_{C} = 70 \text{ °C}$ $T_{A} = 25 \text{ °C}$ $T_{A} = 70 \text{ °C}$ | -<br>ال                           | - 9 <sup>a</sup><br>- 9 <sup>a</sup><br>- 6.8 <sup>b, c</sup><br>- 5.5 <sup>b, c</sup> | A    |  |  |  |  |
| Pulsed Drain Current   |   | I <sub>DM</sub>                   | - 25   |      |  |  |  |  |
| Continuous Source-Drain Diode Current  | $T_{C} = 25 \text{ °C}$ $T_{A} = 25 \text{ °C}$   | ۱ <sub>s</sub>                    | - 9 <sup>a</sup><br>- 2 <sup>b, c</sup>  |      |  |  |  |  |
| Maximum Power Dissipation  | $T_{C} = 25 °C$ $T_{C} = 70 °C$ $T_{A} = 25 °C$ $T_{A} = 70 °C$                                 | P <sub>D</sub> -                  | 13<br>8.4<br>2.4 <sup>b, c</sup><br>1.6 <sup>b, c</sup>                                | W    |  |  |  |  |
| Operating Junction and Storage Temperature Range<br>Soldering Recommendations (Peak Temperature) <sup>d, 6</sup> |   | T <sub>J</sub> , T <sub>stg</sub> | - 55 to 150<br>260   | °C   |  |  |  |  |

| THERMAL RESISTANCE RATINGS                              |              |                   |         |      |      |  |  |  |  |
|---|--------------|-------------------|---------|------|------|--|--|--|--|
| Parameter   | Symbol       | Typical           | Maximum | Unit |      |  |  |  |  |
| Maximum Junction-to-Ambient <sup>b, f</sup> $t \le 5 s$ |              | R <sub>thJA</sub> | 41      | 51   | °C/W |  |  |  |  |
| Maximum Junction-to-Case (Drain)                        | Steady State | R <sub>thJC</sub> | 7.5     | 9.5  | 0/11 |  |  |  |  |

Notes:

a. Package limited.

b. Surface mounted on 1" x 1" FR4 board.

c. t = 5 s.

d. See solder profile (<u>www.vishay.com/doc?73257</u>). The PowerPAK SC-75 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.

f. Maximum under steady state conditions is 105 °C/W.



FREE

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| Parameter                                     | Symbol                  | Test Conditions   | Min.  | Тур.   | Max.  | Unit  |  |  |
|---|-------------------------|---|-------|--------|-------|-------|--|--|
| Static  |                         | · · · · · · · · · · · · · · · · · · ·   |       | •      |       | •     |  |  |
| Drain-Source Breakdown Voltage                | V <sub>DS</sub>         | $V_{GS} = 0 V, I_D = -250 \mu A$  | - 20  |        |       | V     |  |  |
| V <sub>DS</sub> Temperature Coefficient       | $\Delta V_{DS}/T_{J}$   | I <sub>D</sub> = - 250 μA   |       | - 12   |       | mV/°C |  |  |
| V <sub>GS(th)</sub> Temperature Coefficient   | $\Delta V_{GS(th)}/T_J$ | η = - 230 μΑ  |       | 2.5    |       |       |  |  |
| Gate-Source Threshold Voltage                 | V <sub>GS(th)</sub>     | $V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$   | - 0.4 |        | - 1   | V     |  |  |
| Cata Sauraa Laakaga                           | I <sub>GSS</sub>        | $V_{DS} = 0 V$ , $V_{GS} = \pm 8 V$   |       |        | ± 5   | μΑ    |  |  |
| Gate-Source Leakage                           |                         | $V_{DS} = 0 V, V_{GS} = \pm 4.5 V$  |       |        | ± 0.5 |       |  |  |
| Zara Cata Valtaga Drain Current               |                         | $V_{DS} = -20 \text{ V}, V_{GS} = 0 \text{ V}$  |       |        | - 1   |       |  |  |
| Zero Gate Voltage Drain Current               | IDSS                    | $V_{DS}$ = - 20 V, $V_{GS}$ = 0 V, $T_{J}$ = 55 °C  |       |        | - 10  |       |  |  |
| On-State Drain Current <sup>a</sup>           | I <sub>D(on)</sub>      | $V_{DS}{\leq}$ - 5 V, $V_{GS}$ = - 4.5 V  | - 15  |        |       | A     |  |  |
|   |                         | V <sub>GS</sub> = - 4.5 V, I <sub>D</sub> = - 4.8 A   |       | 0.029  | 0.035 |       |  |  |
|   | R <sub>DS(on)</sub>     | $V_{GS} = -2.5 \text{ V}, \text{ I}_{\text{D}} = -4 \text{ A}$ 0.040                                |       |        |       |       |  |  |
| Drain-Source On-State Resistance <sup>a</sup> |                         | V <sub>GS</sub> = - 1.8 V, I <sub>D</sub> = - 3.3 A   |       | 0.060  | 0.079 | Ω     |  |  |
|   |                         | V <sub>GS</sub> = - 1.5 V, I <sub>D</sub> = - 1.5 A   |       | 0.085  | 0.157 |       |  |  |
| Forward Transconductance <sup>a</sup>         | 9 <sub>fs</sub>         | V <sub>DS</sub> = - 10 V, I <sub>D</sub> = - 4.8 A  |       | 16     |       | S     |  |  |
| Dynamic <sup>b</sup>                          |                         | · · · · · · · · · · · · · · · · · · ·   |       | •      |       |       |  |  |
| Total Gate Charge                             | 0                       | $V_{DS} = -10 \text{ V}, V_{GS} = -8 \text{ V}, I_{D} = -6.8 \text{ A}$                             |       | 22     | 44    |       |  |  |
| Cata Caura Ohanna                             | Q <sub>g</sub>          |   |       | 13     | 26    | nC    |  |  |
| Gate-Source Charge                            | Q <sub>gs</sub>         | $V_{DS}$ = - 10 V, $V_{GS}$ = - 4.5 V, $I_D$ = - 6.8 A  |       | 1.2    |       |       |  |  |
| Gate-Drain Charge                             | Q <sub>gd</sub>         |   |       | 3      |       |       |  |  |
| Gate Resistance                               | Rg                      | f = 1 MHz   | 0.28  | 1.4    | 2.8   | kΩ    |  |  |
| Turn-On Delay Time                            | t <sub>d(on)</sub>      |   |       | 0.34   | 0.51  |       |  |  |
| Rise Time                                     | t <sub>r</sub>          | $V_{DD}$ = - 10 V, $R_L$ = 1.8 $\Omega$   |       | 0.90   | 1.35  |       |  |  |
| Turn-Off Delay Time                           | t <sub>d(off)</sub>     | $\text{I}_\text{D}\cong$ - 5.5 A, $\text{V}_\text{GEN}$ = - 4.5 V, $\text{R}_\text{g}$ = 1 $\Omega$ |       | 3      | 4.5   |       |  |  |
| Fall Time                                     | t <sub>f</sub>          |   |       | 1.90   | 2.90  |       |  |  |
| Turn-On Delay Time                            | t <sub>d(on)</sub>      |   |       | 0.17   | 0.26  | μs    |  |  |
| Rise Time                                     | t <sub>r</sub>          | $V_{DD}$ = - 10 V, $R_L$ = 1.8 $\Omega$   |       | 0.45   | 0.70  | -     |  |  |
| Turn-Off Delay Time                           | t <sub>d(off)</sub>     | $\text{I}_\text{D}\cong$ - 5.5 A, $\text{V}_\text{GEN}$ = - 8 V, $\text{R}_\text{g}$ = 1 $\Omega$   |       | 5.5    | 8.30  |       |  |  |
| Fall Time                                     | t <sub>f</sub>          |   |       | 2      | 3.5   | 1     |  |  |
| Drain-Source Body Diode Characteristi         | cs                      | ·   |       |        | ·     | ·     |  |  |
| Continuous Source-Drain Diode Current         | ا <sub>S</sub>          | $T_{\rm C} = 25 \ ^{\circ}{\rm C}$  |       |        | - 9   | A     |  |  |
| Pulse Diode Forward Current                   | I <sub>SM</sub>         |   |       |        | - 25  |       |  |  |
| Body Diode Voltage                            | V <sub>SD</sub>         | I <sub>S</sub> = - 5.5 A, V <sub>GS</sub> = 0 V   |       | - 0.85 | - 1.2 | V     |  |  |

Notes:

a. Pulse test; pulse width  $\leq$  300  $\mu s,$  duty cycle  $\leq$  2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

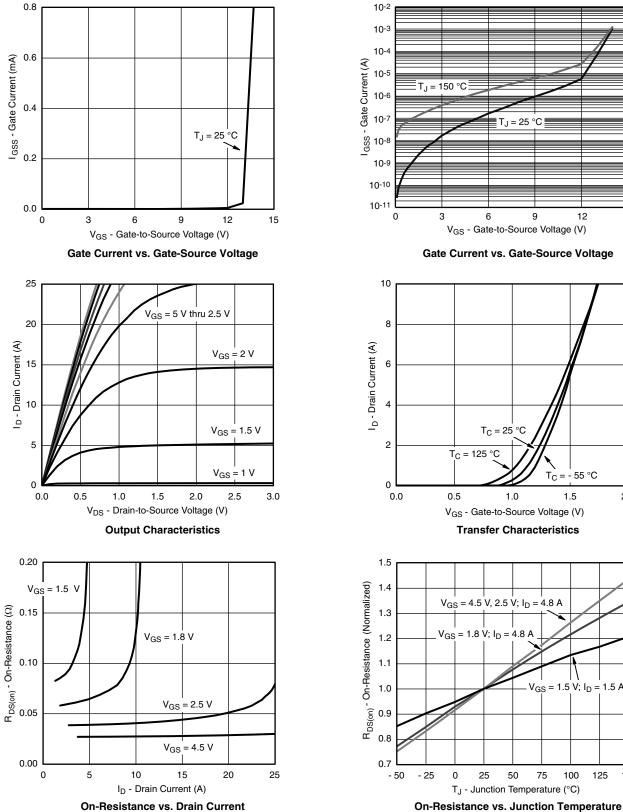


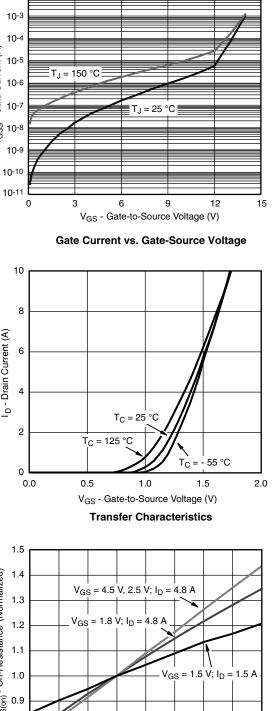
Document Number: 64816

S12-0497-Rev. C, 05-Mar-12

## SiB457EDK Vishay Siliconix

### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)





For more information please contact: pmostechsupport@vishay.com www.vishay.com

0

25

50

T<sub>J</sub> - Junction Temperature (°C)

75

100

125

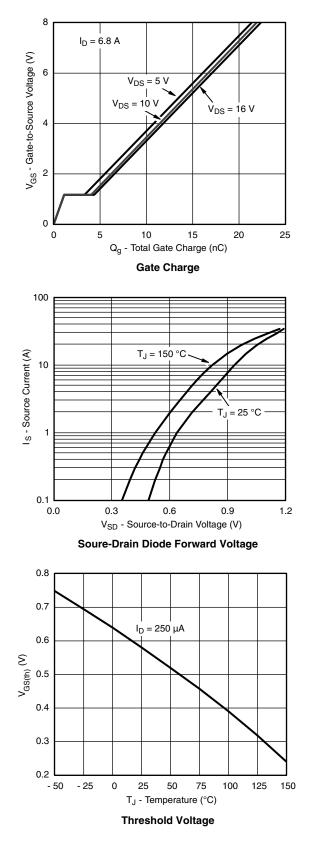
150

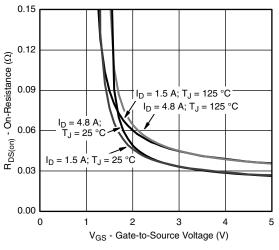
3

### **Vishay Siliconix**

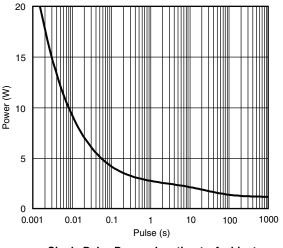


### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

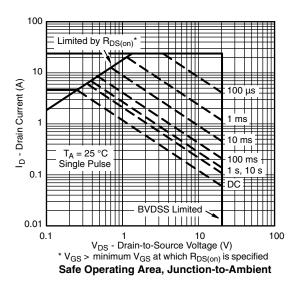




**On-Resistance vs. Gate-to-Source Voltage** 







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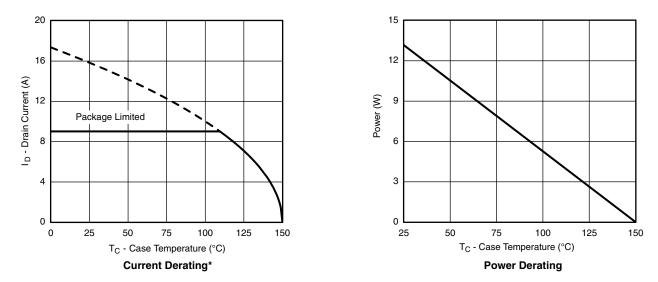
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### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



\* The power dissipation  $P_D$  is based on  $T_{J(max)} = 150$  °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

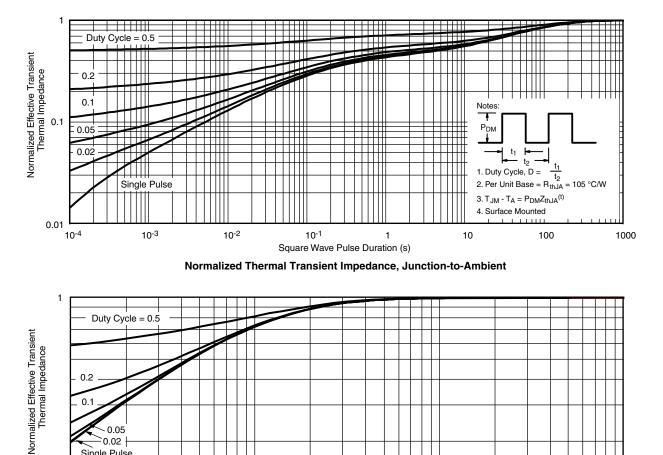


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- 0.05 <sup>≥</sup>0.02 Single Pulse

0.1 10-4

### TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



10<sup>-3</sup>

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?64816.

Square Wave Pulse Duration (s) Normalized Thermal Transient Impedance, Junction-to-Case

10-2

www.vishay.com 6

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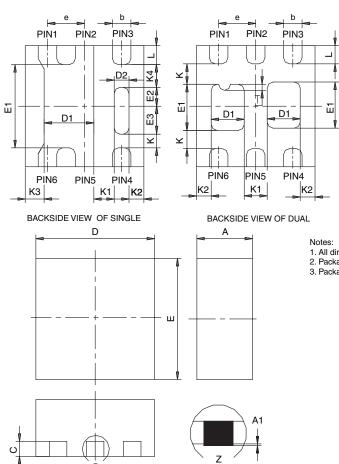
10-1

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# Package Information

# Vishay Siliconix





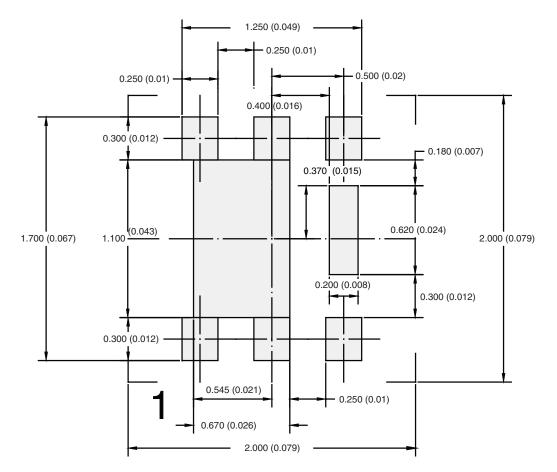
- All dimensions are in millimeters
   Package outline exclusive of mold flash and metal burr
   Package outline inclusive of plating

DETAIL Z

|   |                     | SINGLE PAD          |      |                   |           |           |             | DUAL PAD  |           |           |       |       |  |
|---|---------------------|---------------------|------|-------------------|-----------|-----------|-------------|-----------|-----------|-----------|-------|-------|--|
| DIM   | MILLIMETERS         |                     |      | INCHES            |           |           | MILLIMETERS |           |           | INCHES    |       |       |  |
|   | Min                 | Nom                 | Max  | Min               | Nom       | Max       | Min         | Nom       | Max       | Min       | Nom   | Max   |  |
| Α   | 0.675               | 0.75                | 0.80 | 0.027             | 0.030     | 0.032     | 0.675       | 0.75      | 0.80      | 0.027     | 0.030 | 0.032 |  |
| A1  | 0                   | -                   | 0.05 | 0                 | -         | 0.002     | 0           | -         | 0.05      | 0         | -     | 0.002 |  |
| b   | 0.18                | 0.25                | 0.33 | 0.007             | 0.010     | 0.013     | 0.18        | 0.25      | 0.33      | 0.007     | 0.010 | 0.013 |  |
| С   | 0.15                | 0.20                | 0.25 | 0.006             | 0.008     | 0.010     | 0.15        | 0.20      | 0.25      | 0.006     | 0.008 | 0.010 |  |
| D   | 1.53                | 1.60                | 1.70 | 0.060             | 0.063     | 0.067     | 1.53        | 1.60      | 1.70      | 0.060     | 0.063 | 0.067 |  |
| D1  | 0.57                | 0.67                | 0.77 | 0.022             | 0.026     | 0.030     | 0.34        | 0.44      | 0.54      | 0.013     | 0.017 | 0.021 |  |
| D2  | 0.10                | 0.20                | 0.30 | 0.004             | 0.008     | 0.012     |             |           |           |           |       |       |  |
| Е   | 1.53                | 1.60                | 1.70 | 0.060             | 0.063     | 0.067     | 1.53        | 1.60      | 1.70      | 0.060     | 0.063 | 0.067 |  |
| E1  | 1.00                | 1.10                | 1.20 | 0.039             | 0.043     | 0.047     | 0.51        | 0.61      | 0.71      | 0.020     | 0.024 | 0.028 |  |
| E2  | 0.20                | 0.25                | 0.30 | 0.008             | 0.010     | 0.012     |             |           |           |           |       |       |  |
| E3  | 0.32                | 0.37                | 0.42 | 0.013             | 0.015     | 0.017     |             |           |           |           |       |       |  |
| е   |                     | 0.50 BSC            |      |                   | 0.020 BSC |           | 0.50 BSC    |           |           | 0.020 BSC |       |       |  |
| К   |                     | 0.180 TYP 0.007 TYP |      |                   |           | 0.245 TYP |             |           | 0.010 TYP |           |       |       |  |
| K1  |                     | 0.275 TYP           |      |                   | 0.011 TYP |           | 0.320 TYP   |           |           | 0.013 TYP |       |       |  |
| K2  | 0.200 TYP 0.008 TYP |                     |      | 0.200 BSC 0.008 T |           |           |             | 0.008 TYP |           |           |       |       |  |
| K3  | 0.255 TYP 0.010 TYP |                     |      |                   |           |           |             |           |           |           |       |       |  |
| K4  | 0.300 TYP           |                     |      | 0.012 TYP         |           |           |             |           |           |           |       |       |  |
| L   | 0.15                | 0.25                | 0.35 | 0.006             | 0.010     | 0.014     | 0.15        | 0.25      | 0.35      | 0.006     | 0.010 | 0.014 |  |
| Т   |                     |                     |      |                   |           |           | 0.03        | 0.08      | 0.13      | 0.001     | 0.003 | 0.005 |  |
| ECN: C-07431 – Rev. C, 06-Aug-07<br>DWG: 5935 |                     |                     |      |                   |           |           |             |           |           |           |       |       |  |



### RECOMMENDED PAD LAYOUT FOR PowerPAK<sup>®</sup> SC75-6L Single



Dimensions in mm/(Inches)

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